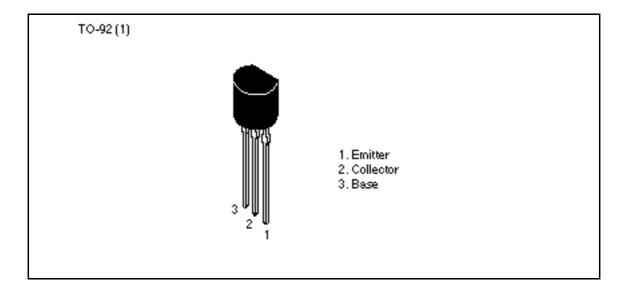
Silicon NPN Epitaxial

HITACHI

Application

- Low frequency low noise amplifier
- Complementary pair with 2SA1083, 2SA1084 and 2SA1085

Outline





Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

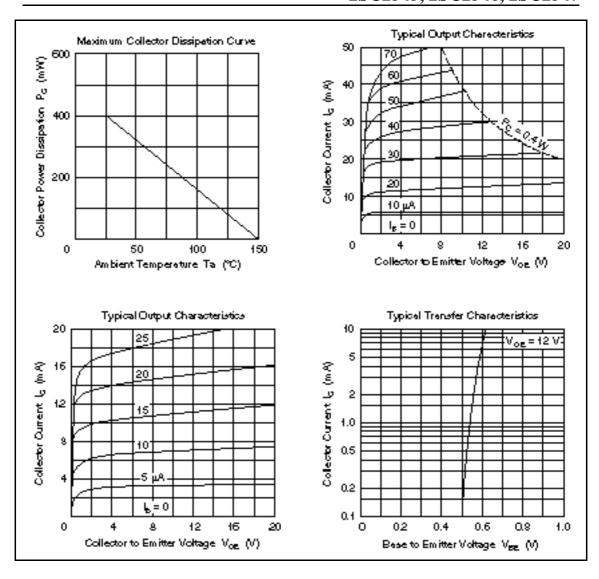
Item	Symbol	2SC2545	2SC2546	2SC2547	Unit
Collector to base voltage	V_{CBO}	60	90	120	V
Collector to emitter voltage	V_{CEO}	60	90	120	V
Emitter to base voltage	V_{EBO}	5	5	5	V
Collector current	I _c	100	100	100	mA
Emitter current	I _E	-100	-100	-100	mA
Collector power dissipation	P _c	400	400	400	mW
Junction temperature	Tj	150	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	°C

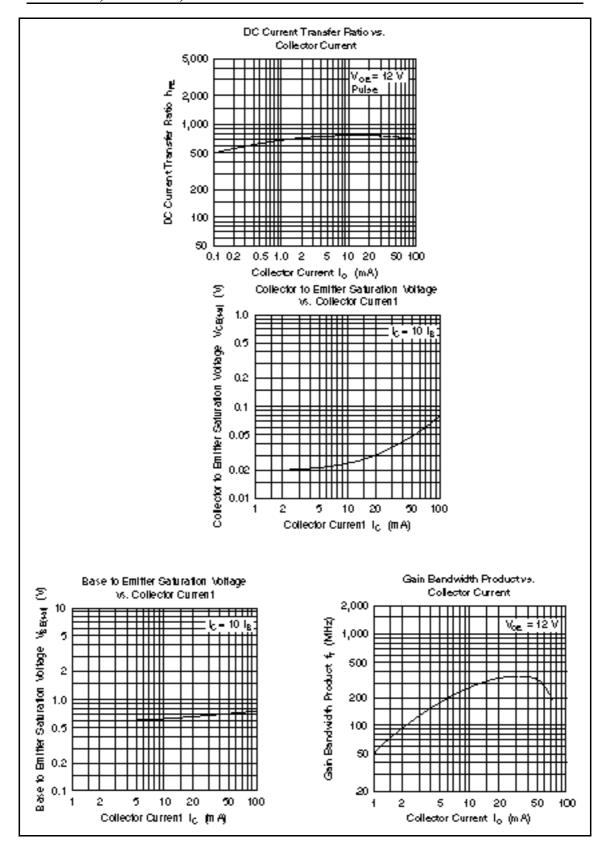
Electrical Characteristics ($Ta = 25^{\circ}C$)

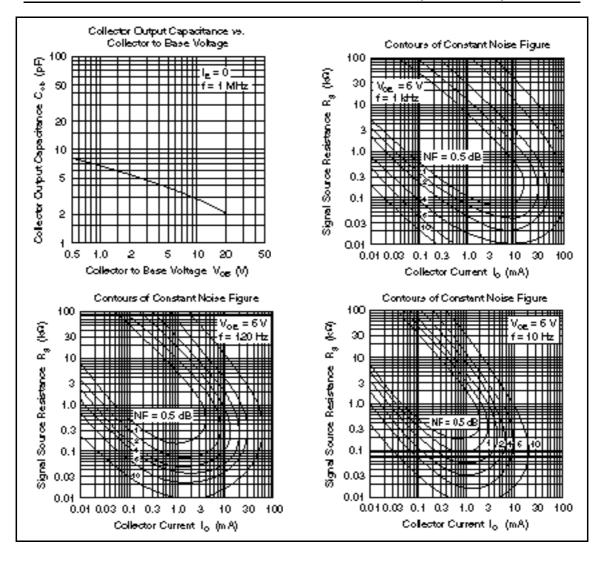
		2SC2545 2SC2546		2SC2547								
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	60	_	_	90	_	_	120	_	_	V	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	60	_	_	90	_	_	120	_	_	V	$I_C = 1 \text{ mA},$ $R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	5	_	_	5	_	_	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I _{CBO}	_	_	0.1	_	_	0.1	_	_	0.1	μΑ	$V_{CB} = 50 \text{ V}, I_{E} = 0$
Emitter cutoff current	I _{EBO}	_	_	0.1	_	_	0.1	_	_	0.1	μΑ	$V_{EB} = 2 \text{ V}, I_{C} = 0$
DC current transfer ratio	h _{FE} *1	250	_	1200	250	_	1200	250	_	800		$V_{CE} = 12 \text{ V},$ $I_{C} = 2 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	0.2	_	_	0.2	_	_	0.2	V	$I_C = 10 \text{ mA},$ $I_B = 1 \text{ mA}$
Base to emitter voltage	V_{BE}	_	0.6	_	_	0.6	_	_	0.6	_	V	$V_{CE} = 12 \text{ V},$ $I_{C} = 2 \text{ mA}$
Gain bandwidth product	f _T	_	90	_	_	90	_	_	90	_	MHz	$V_{CE} = 12 \text{ V},$ $I_{C} = 2 \text{ mA}$
Collector output capacitance	Cob	_	3.0	_	_	3.0	_	_	3.0	_	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0,$ f = 1 MHz
Noise voltage referred input	e _n	_	0.5	_	_	0.5	_	_	0.5	_	nV/ Hz	$V_{CE} = 6V,$ $I_{C} = 10 \text{ mA},$ $f = 1 \text{ kHz},$ $R_{g} = 0, f = 1 \text{Hz}$

Note: 1. The 2SC2545, 2SC2546 and 2SC2547 are grouped by h_{FE} as follows.

	D	E	F
2SC2545, 2SC2546	250 to 500	400 to 800	600 to 1200
2SC2547	250 to 500	400 to 800	_







When using this document, keep the following in mind:

- 1. This document may, wholly or partially, be subject to change without notice.
- 2. All rights are reserved: No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without Hitachi's permission.
- 3. Hitachi will not be held responsible for any damage to the user that may result from accidents or any other reasons during operation of the user's unit according to this document.
- 4. Circuitry and other examples described herein are meant merely to indicate the characteristics and performance of Hitachi's semiconductor products. Hitachi assumes no responsibility for any intellectual property claims or other problems that may result from applications based on the examples described herein.
- 5. No license is granted by implication or otherwise under any patents or other rights of any third party or Hitachi, Ltd.
- 6. MEDICAL APPLICATIONS: Hitachi's products are not authorized for use in MEDICAL APPLICATIONS without the written consent of the appropriate officer of Hitachi's sales company. Such use includes, but is not limited to, use in life support systems. Buyers of Hitachi's products are requested to notify the relevant Hitachi sales offices when planning to use the products in MEDICAL APPLICATIONS.

HITACHI

Hitachi, Ltd.
Semiconductor & IC Div.
Nippon Bidg., 2-6-2, Ohte-medii, Chiyode-ku, Tokyo 100, Jepen Tet Tokyo (03, 3270-2111
Fex: (03, 3270-5109)

For further in forms florr write to: Histori Americe, Ltd. Semiconductor & IC DW. 2000 Sierre Point Pertwey Briebere, CA. 94005-1835 U.S.A. Tet 445-589-8300

Fax: 415-583-4207

Bedronic Components Group Continental Burope Domecher Streße 3 D-85822 Feldkindhen München Tet 089-9 94 80-0 Fex: 089-9 29 30 00

Hitechi Burope GmbH

Hitschi Burope Ltd.
Bedronie Components Dv.
Northern Burope Hesidquerters
Whitebrook Ferk
Lower Cook ham Road
Maidenheed
Berkshire SL68YA
United Kingdom
Tet 0628-885000
Fex 0628-778322

Hitschi Asia Pte. Ltd 45 Collyer Quey \$20-00 Hitschi Tower Singapore 0104 Tet 535-2100 Fex: 535-1533

Hischi Asia (Hong Kong) Ltd. Unit 705, North Towar, World Finance Centre, Harbour City, Centon Road Taim She Taul, Kowloon Hong Kong Tet 27:350218 Fax: 27:30607 f